

/ Descriptions

Silicon NPN transistor in a TO-18 Plastic Package.

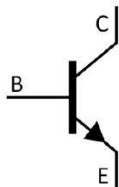
/ Features

Complement to BD140.

/ Applications

Medium power linear and switching applications.

/ Equivalent Circuit



/ Pinning



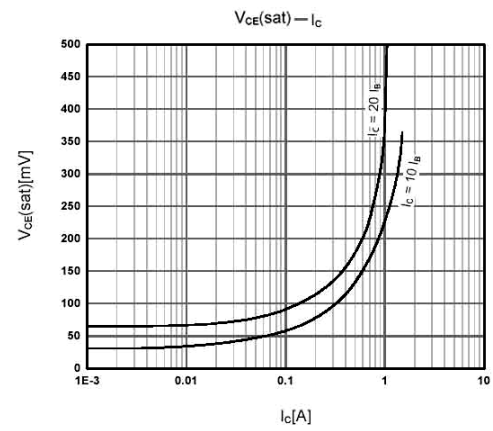
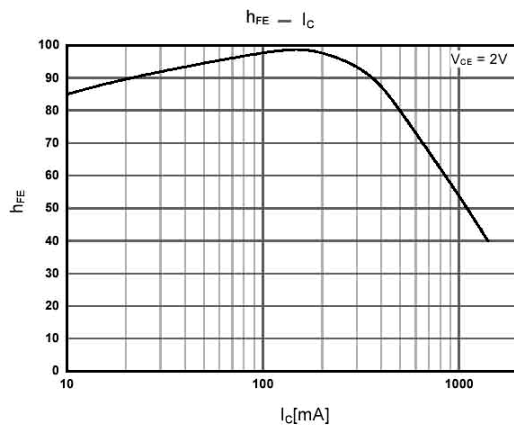
PIN1 Emitter PIN 2 Collector PIN 3 Base

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	6	10	16	25
h_{FE} Range	40 100	63 160	100 250	160 400

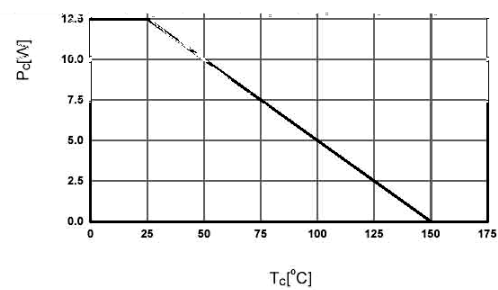
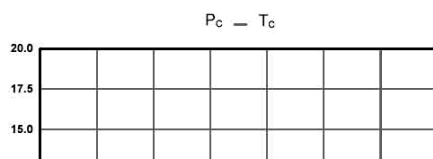
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	80	V
Collector to Emitter Voltage	V_{CEO}	80	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.5	A
Collector Current – Continuous	I_{CP}	3.0	A
Base Current – Continuous	I_B	0.5	A
Collector Power Dissipation	P_C	1.25	W
Collector Power Dissipation	$P_C(T_c=25^\circ C)$	12.5	W
Junction Temperature	T_J	150	$^{\circ}C$

/ **Electrical Characteristic Curve**



$V_{BE} - I_C$

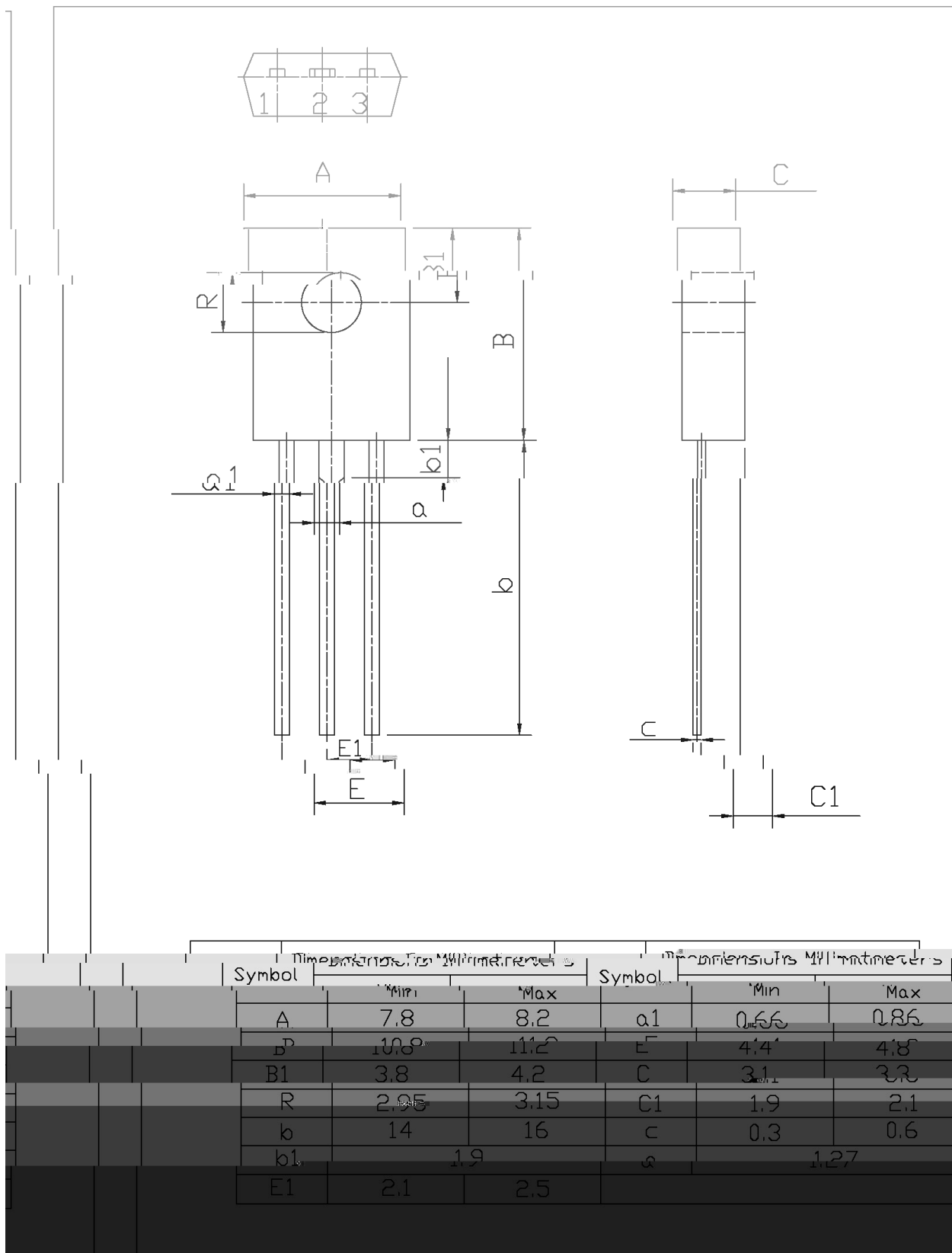
$I_C - V_{CE}$



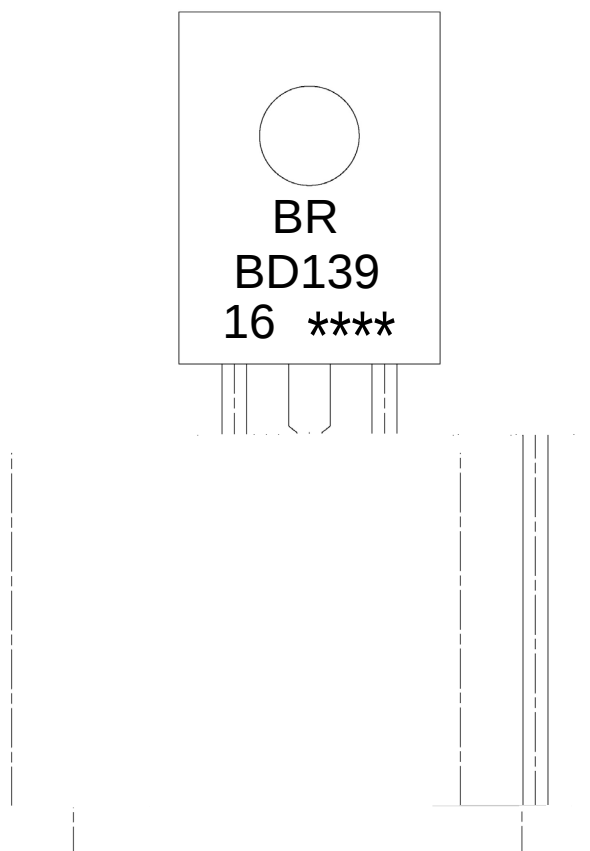
/ Package Dimensions

BU-126T

单位: mm



/ Marking Instructions



Note:

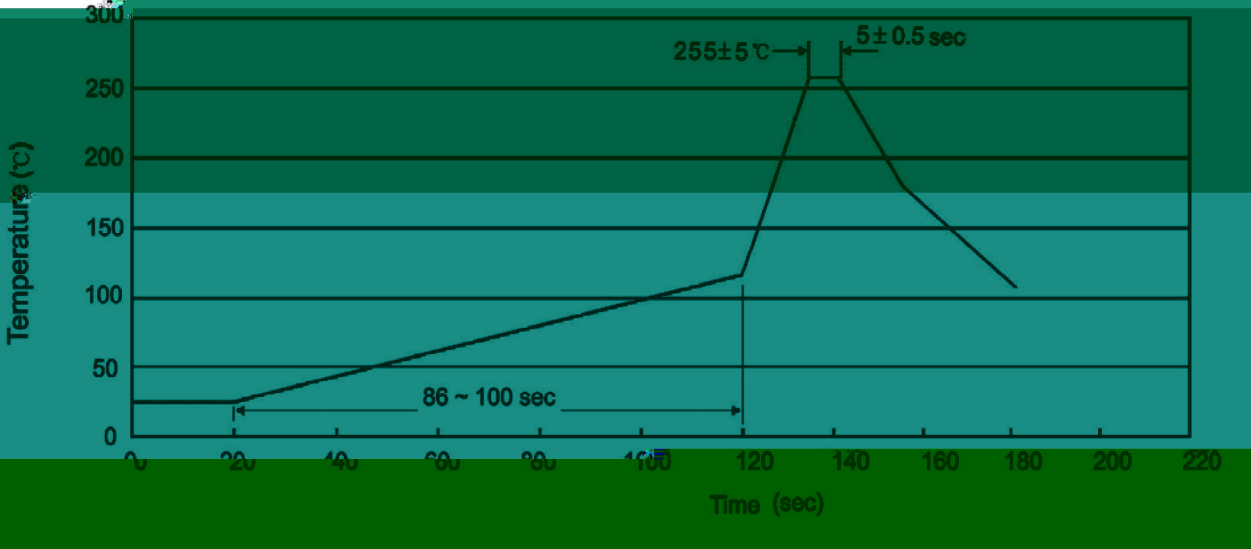
BR: Company Code

BD139: Product Type.

16: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255 5

5 0.5sec;
- 3

2 10

/sec.
- 1.Preheating:25~150

, Time:60~90sec.
- 2.Peak Temp.:255 5

, Duration:5 0.5sec.
3. Cooling Speed: 2~10

/sec.

/ Resistance to Soldering Heat Test Conditions

270 5 10 1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box